

Features

- Trench LV MOSFET Technology
- High Power and Current Handing Capability
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

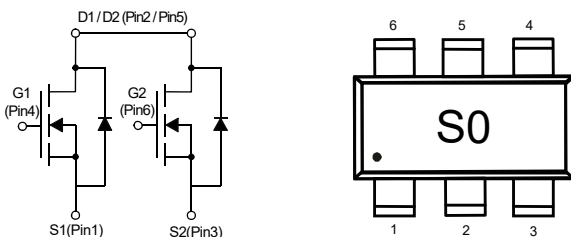
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 89.5°C/W Junction to Ambient (Note 2)

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	V_{DS}	20	V	
Gate-Source Voltage	V_{GS}	±10	V	
Continuous Drain Current	I_D	$T_A=25^\circ\text{C}$	4	A
		$T_A=100^\circ\text{C}$	2.5	
Pulsed Drain Current (Note 3)	I_{DM}	16	A	
Total Power Dissipation (Note 4)	P_D	1.4	W	

Note:

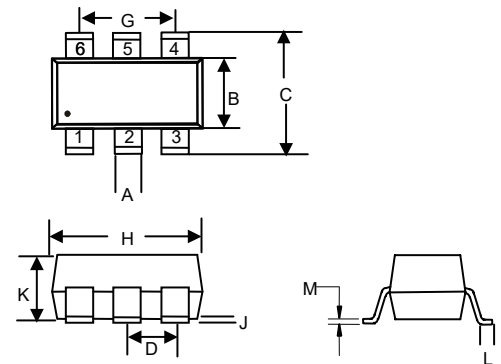
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

Internal Structure and Marking Code



Dual N-Channel Mosfet

SOT23-6L



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.012	0.020	0.30	0.50	
B	0.051	0.070	1.30	1.80	
C	0.087	0.126	2.20	3.20	
D	0.037		0.95		TYP.
G	0.074		1.90		TYP.
H	0.106	0.122	2.70	3.10	
J	0.002	0.006	0.05	0.15	
K	0.030	0.051	0.75	1.30	
L	0.012	0.024	0.30	0.60	
M	0.003	0.008	0.08	0.22	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	20			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 10V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.45	0.7	1	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=4A$		17	25	m Ω
		$V_{GS}=2.5V, I_D=3.5A$		21	32	
		$V_{GS}=1.8V, I_D=2.7A$		29	49	
Forward Transconductance	g_{FS}	$V_{DS}=5V, I_D=4A$		21		S
Gate Resistance	R_g	f=1 MHz, Open drain		2.3		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				4	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=4A$			1.2	V
Reverse Recovery Time	t_{rr}	$I_F=4A, di/dt=100A/\mu s$		12		ns
Reverse Recovery Charge	Q_{rr}			3.6		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=10V, V_{GS}=0V, f=1MHz$		384		pF
Output Capacitance	C_{oss}			69		
Reverse Transfer Capacitance	C_{riss}			60		
Total Gate Charge	Q_g	$V_{DS}=10V, V_{GS}=4.5V, I_D=4A$		5.4		nC
Gate-Source Charge	Q_{gs}			0.6		
Gate-Drain Charge	Q_{gd}			1.5		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, V_{GS}=4.5V, R_G=3\Omega, I_D=4A$		4.3		ns
Turn-On Rise Time	t_r			6.5		
Turn-Off Delay Time	$t_{d(off)}$			16		
Turn-Off Fall Time	t_f			5.1		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

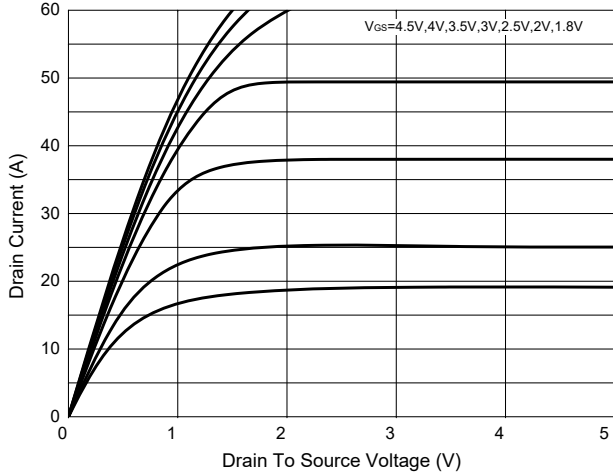


Fig. 2 - Transfer Characteristics

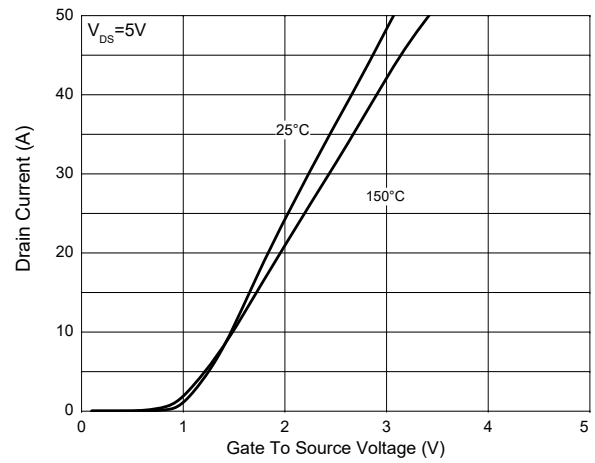


Fig.3 - $R_{DS(ON)} - V_{GS}$

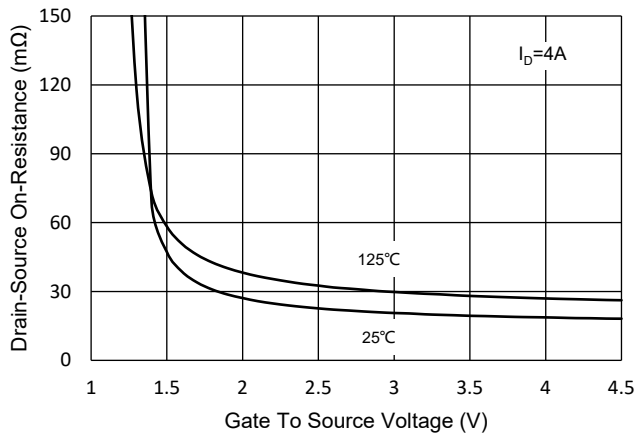


Fig. 4 - $R_{DS(ON)} - I_D$

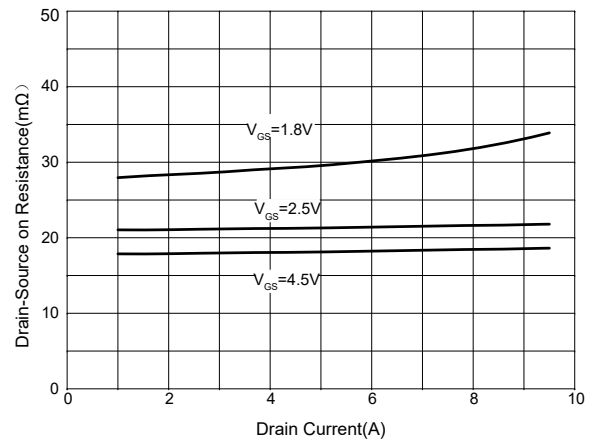


Fig.5 - Capacitance Characteristics

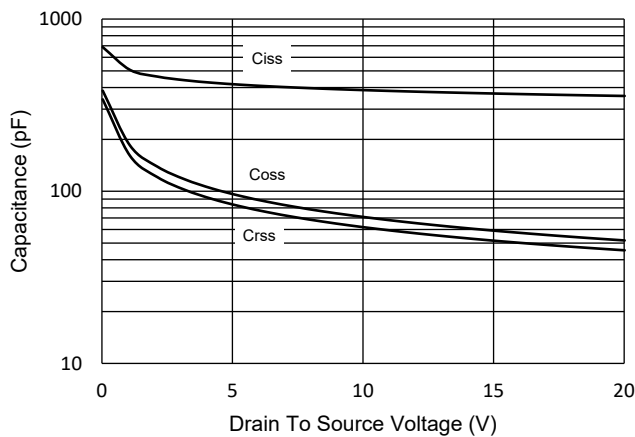
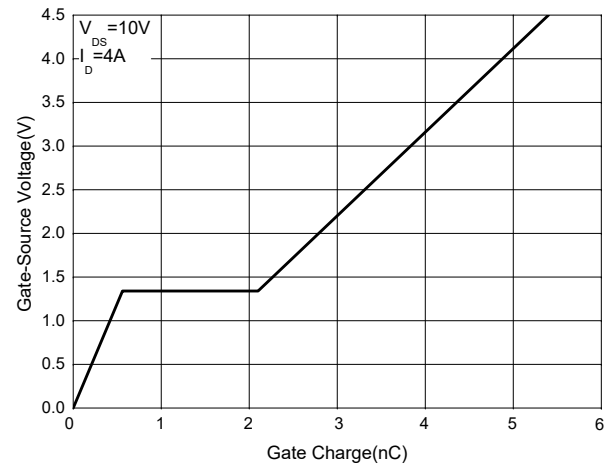


Fig. 6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

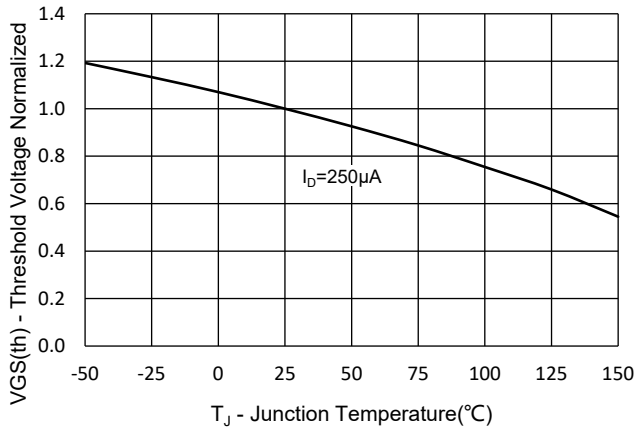


Fig.8 - Normalized On Resistance Characteristics

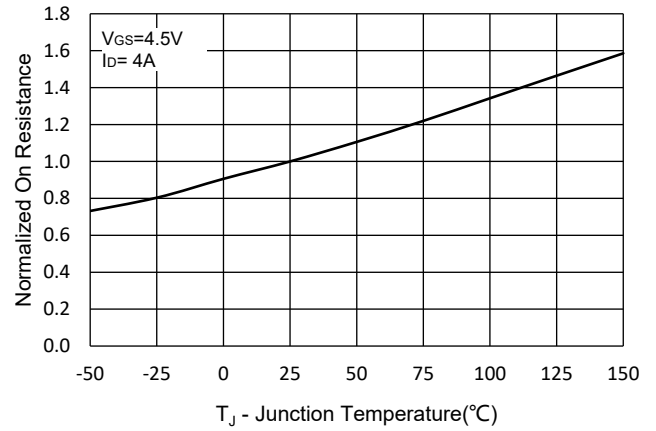


Fig.9 - $I_S - V_{SD}$

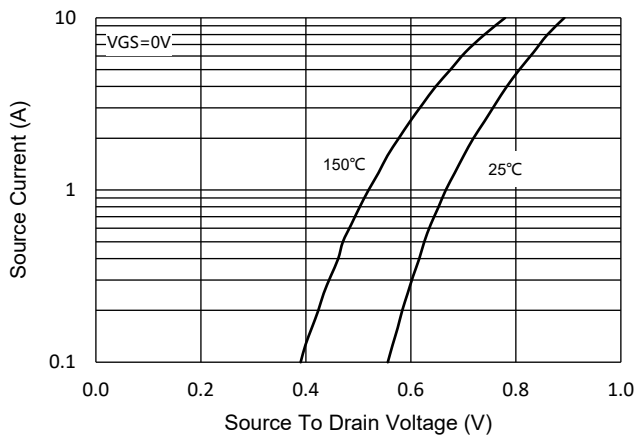


Fig.10 - Drain Current

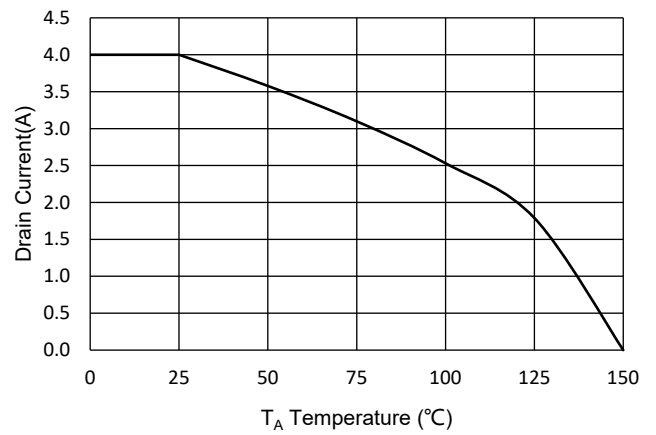
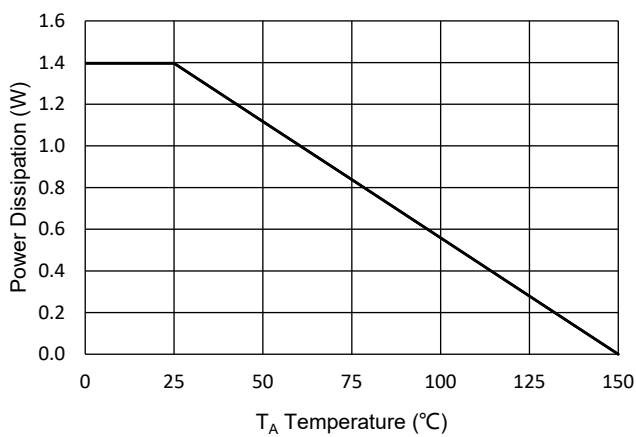


Fig.11 - PD Dissipation



Curve Characteristics

Fig.12 - Safe Operation Area

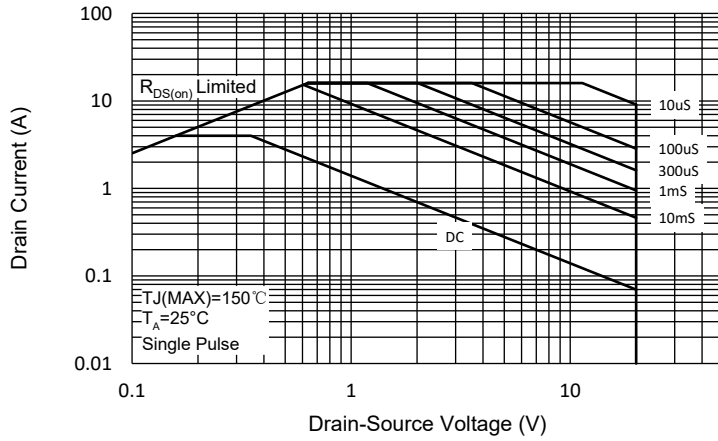
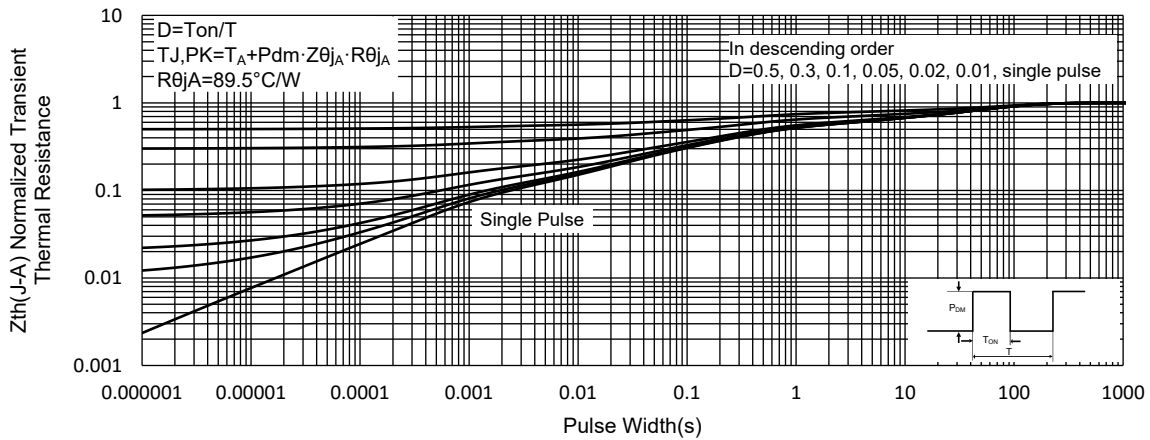


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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